

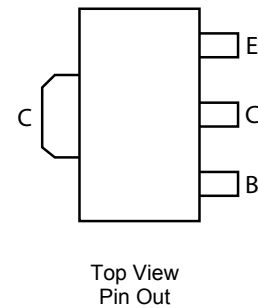
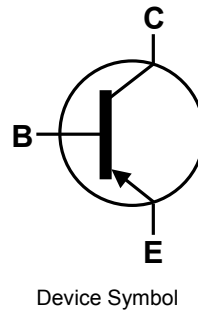
**25V PNP MEDIUM POWER TRANSISTOR IN SOT89**

**Features**

- $BV_{CEO} > -25V$
- $I_C = -3A$  high Continuous Current
- $I_{CM} = -8A$  Peak Pulse Current
- Low saturation voltage  $V_{CE(sat)} < -320mV @ -3A$
- $h_{FE}$  specified up to -8A for high current gain hold up
- Complementary NPN Type: FCX688B
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.05 grams (Approximate)

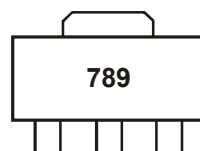


**Ordering Information** (Note 4)

| Product   | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-----------|---------|--------------------|-----------------|-------------------|
| FCX789ATA | 789     | 7                  | 12              | 1,000             |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com>.

**Marking Information**



789 = Product Type Marking Code

### Maximum Ratings (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic               | Symbol    | Limit | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage       | $V_{CBO}$ | -25   | V    |
| Collector-Emitter Voltage    | $V_{CEO}$ | -25   | V    |
| Emitter-Base Voltage         | $V_{EBO}$ | -7    | V    |
| Continuous Collector Current | $I_C$     | -3    | A    |
| Peak Pulse Current           | $I_{CM}$  | -8    | A    |

### Thermal Characteristics (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

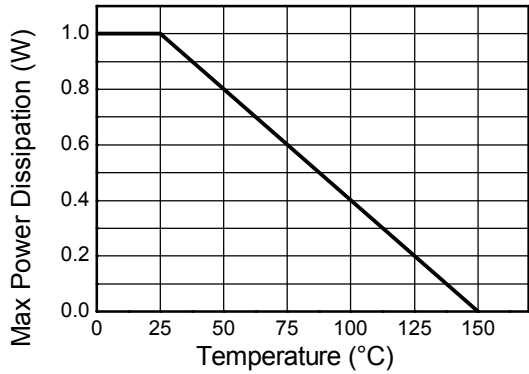
| Characteristic                              | Symbol          | Value            | Unit               |
|---------------------------------------------|-----------------|------------------|--------------------|
| Power Dissipation                           | $P_D$           | (Note 5)<br>1    | W                  |
|                                             |                 | (Note 6)<br>2    |                    |
| Thermal Resistance, Junction to Ambient Air | $R_{\theta JA}$ | (Note 5)<br>125  | $^\circ\text{C/W}$ |
|                                             |                 | (Note 6)<br>62.5 |                    |
| Thermal Resistance, Junction to Leads       | $R_{\theta JL}$ | 5.31             | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range     | $T_J, T_{STG}$  | -55 to +150      | $^\circ\text{C}$   |

### ESD Ratings (Note 8)

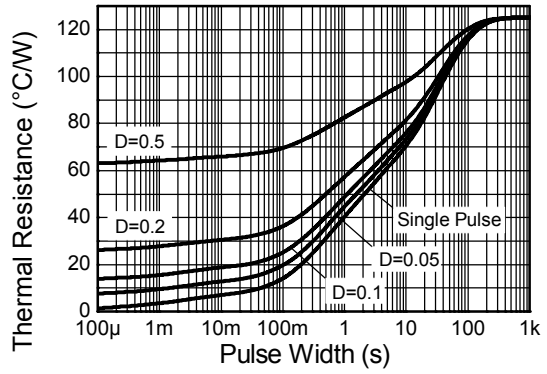
| Characteristic                             | Symbol  | Value      | Unit | JEDEC Class |
|--------------------------------------------|---------|------------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000      | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | $\geq 400$ | V    | C           |

- Notes:
5. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
  6. Same as note (5), except the device is mounted on 40mm X 40mm FR4 PCB.
  7. Thermal resistance from junction to solder-point (at the end of collector lead).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

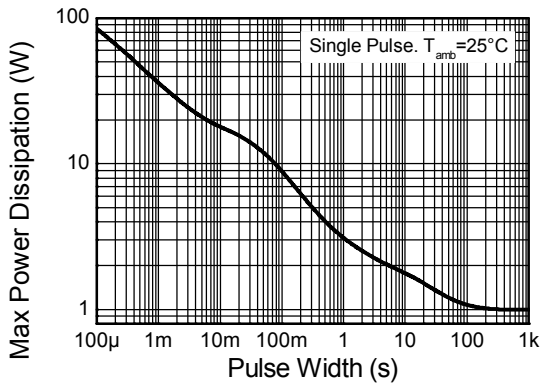
**Thermal Characteristics and Derating Information**



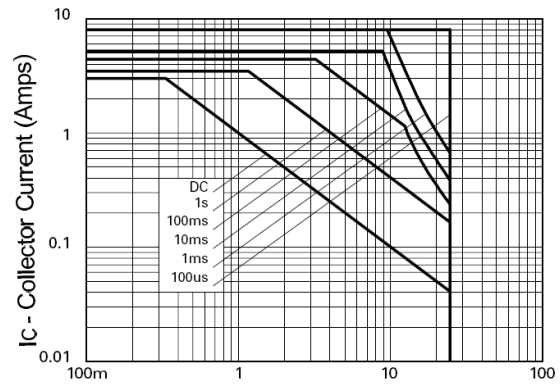
**Derating Curve**



**Transient Thermal Impedance**



**Pulse Power Dissipation**



**V<sub>CE</sub> - Collector Voltage (Volts)**

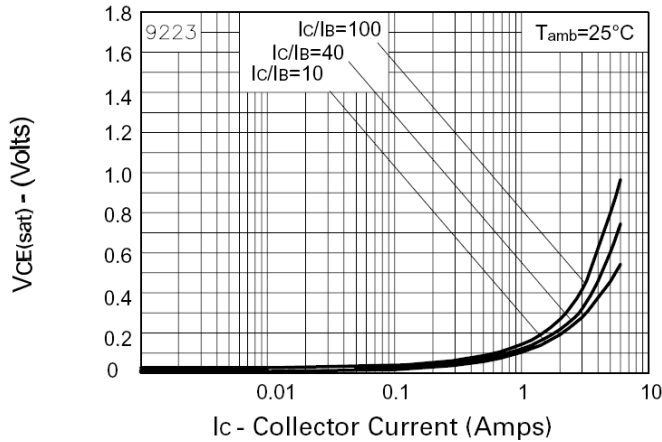
**Safe Operating Area**

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

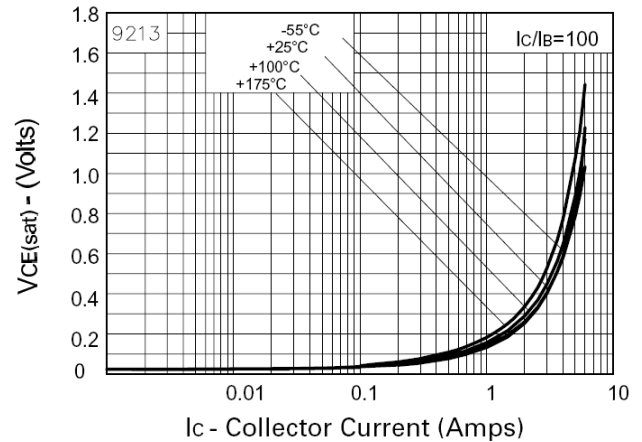
| Characteristic                                | Symbol               | Min                     | Typ.                     | Max                  | Unit | Test Condition                                                                                                                                                                             |
|-----------------------------------------------|----------------------|-------------------------|--------------------------|----------------------|------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Collector-Base Breakdown Voltage              | BV <sub>CBO</sub>    | -25                     | -                        | -                    | V    | I <sub>C</sub> = -100μA                                                                                                                                                                    |
| Collector-Emitter Breakdown Voltage (Note 9)  | BV <sub>CEO</sub>    | -25                     | -                        | -                    | V    | I <sub>C</sub> = -10mA                                                                                                                                                                     |
| Emitter-Base Breakdown Voltage                | BV <sub>EBO</sub>    | -7                      | -8.1                     | -                    | V    | I <sub>E</sub> = -100μA                                                                                                                                                                    |
| Collector Cutoff Current                      | I <sub>CBO</sub>     | -                       | <1                       | -100                 | nA   | V <sub>CB</sub> = -15V                                                                                                                                                                     |
| Emitter Cutoff Current                        | I <sub>EBO</sub>     | -                       | <1                       | -100                 | nA   | V <sub>EB</sub> = -5.6V                                                                                                                                                                    |
| DC current transfer Static ratio (Note 9)     | h <sub>FE</sub>      | 300<br>230<br>180<br>75 | 500<br>320<br>250<br>120 | 800<br>-<br>-<br>-   | -    | I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V<br>I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V<br>I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V<br>I <sub>C</sub> = -6A, V <sub>CE</sub> = -2V |
| Collector-Emitter Saturation Voltage (Note 9) | V <sub>CE(sat)</sub> | -<br>-<br>-             | -130<br>-290<br>-250     | -190<br>-400<br>-320 | mV   | I <sub>C</sub> = -1A, I <sub>B</sub> = -10mA<br>I <sub>C</sub> = -2A, I <sub>B</sub> = -20mA<br>I <sub>C</sub> = -3A, I <sub>B</sub> = -100mA                                              |
| Base-Emitter Saturation Voltage (Note 9)      | V <sub>BE(sat)</sub> | -                       | -0.8                     | -0.9                 | V    | I <sub>C</sub> = -1A, I <sub>B</sub> = -10mA                                                                                                                                               |
| Base-Emitter Turn-on Voltage (Note 9)         | V <sub>BE(on)</sub>  | -                       | -0.8                     | -                    | V    | I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V                                                                                                                                                |
| Transitional Frequency                        | f <sub>T</sub>       | 100                     | -                        | -                    | MHz  | I <sub>C</sub> = -50mA, V <sub>CE</sub> = -5V<br>f = 50MHz                                                                                                                                 |
| Input capacitance                             | C <sub>ibo</sub>     | -                       | 225                      | -                    | pF   | V <sub>EB</sub> = -0.5V, f = 1MHz,                                                                                                                                                         |
| Output capacitance                            | C <sub>obo</sub>     | -                       | 25                       | -                    | pF   | V <sub>CB</sub> = -10V, f = 1MHz,                                                                                                                                                          |
| Switching times                               | t <sub>on</sub>      | -                       | 35                       | -                    | nS   | I <sub>C</sub> = -500mA, V <sub>CC</sub> = -10V<br>I <sub>B1</sub> = -I <sub>B2</sub> = -50mA                                                                                              |
|                                               | t <sub>off</sub>     | -                       | 400                      | -                    | nS   |                                                                                                                                                                                            |

Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

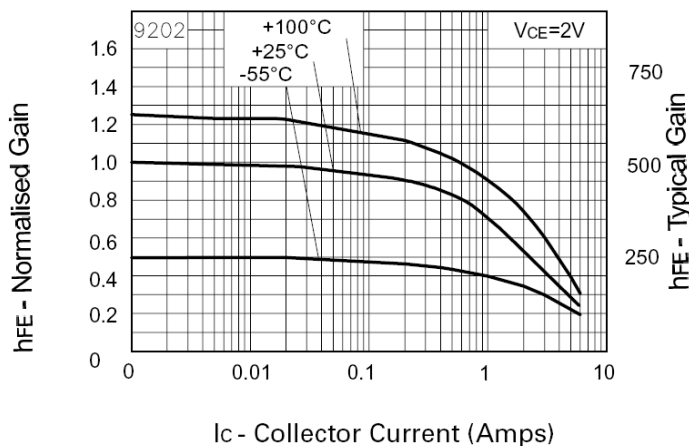
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



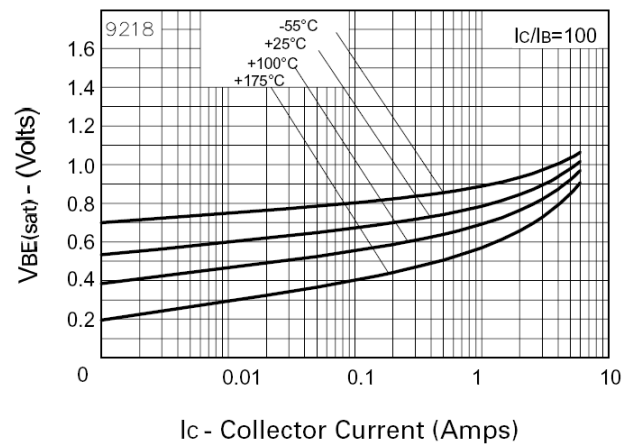
VCE(sat) v IC



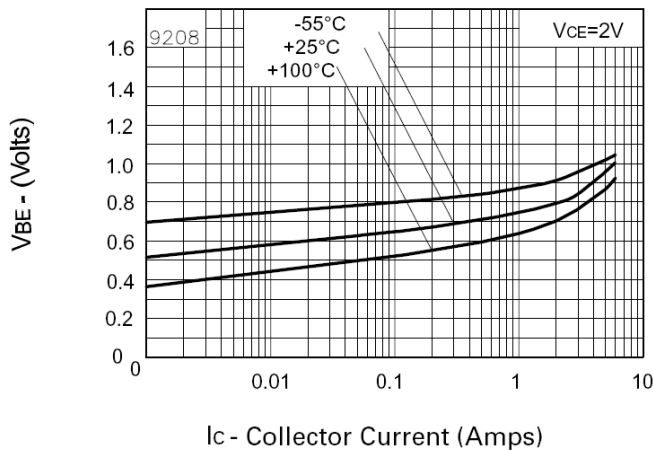
VCE(sat) v IC



hFE v IC



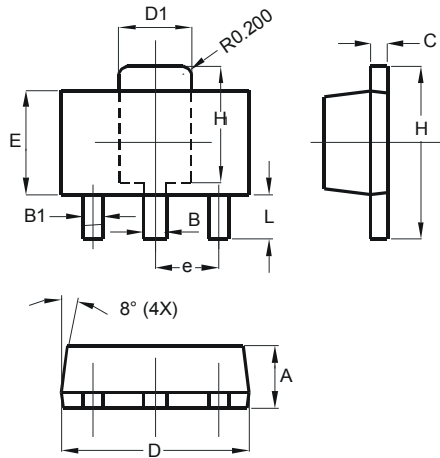
VBE(sat) v IC



VBE(on) v IC

## Package Outline Dimensions

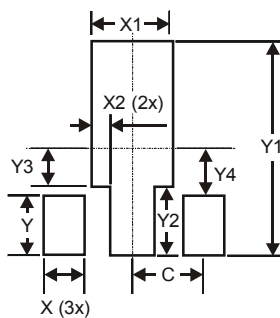
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| SOT89                |          |      |
|----------------------|----------|------|
| Dim                  | Min      | Max  |
| A                    | 1.40     | 1.60 |
| B                    | 0.44     | 0.62 |
| B1                   | 0.35     | 0.54 |
| C                    | 0.35     | 0.44 |
| D                    | 4.40     | 4.60 |
| D1                   | 1.62     | 1.83 |
| E                    | 2.29     | 2.60 |
| e                    | 1.50 Typ |      |
| H                    | 3.94     | 4.25 |
| H1                   | 2.63     | 2.93 |
| L                    | 0.89     | 1.20 |
| All Dimensions in mm |          |      |

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| X          | 0.900         |
| X1         | 1.733         |
| X2         | 0.416         |
| Y          | 1.300         |
| Y1         | 4.600         |
| Y2         | 1.475         |
| Y3         | 0.950         |
| Y4         | 1.125         |
| C          | 1.500         |

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